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Local stress and superfluid properties of solid $^4$He

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More than half a century ago Penrose asked [1]: are the superfluid and solid state of matter mutually exclusive or do there exist “supersolid” materials where the atoms form a regular lattice and simultaneously flow without friction? Recent experiments provide evidence that supersolid behavior indeed exists in $^4$He – the most quantum material known in Nature. In this paper we show that large local strain in the vicinity of crystalline defects is the origin of supersolidity in $^4$He.

Although ideal crystals of $^4$He are not supersolid, the gap for vacancy creation closes when applying a moderate stress. While a homogeneous system simply becomes unstable at this point, the stressed core of crystalline defects (dislocations and grain boundaries) undergoes a radical transformation and can become superfluid.

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The first microscopic mechanism of supersolidity was proposed by Andreev, Lifshitz [2] and Chester [3] arguing that a dilute gas of vacancies could lower the energy of an ideal helium crystal by quantum mechanically delocalizing vacancies. At low enough temperature the vacancies then undergo Bose-Einstein condensation and give rise to a supersolid – and indeed vacancies are required for supersolidity [4]. Although detection of frictionless mass flow was anticipated to be straightforward, all experimental attempts failed for over thirty years [5] until Kim and Chan reported the observation of an unexpected drop of the torsional oscillator period at low temperatures [6, 7]. Since the period is proportional to the square root of the moment of inertia, the origin of the period shift was attributed to the supersolid decoupling of the $^4$He solid mass from the rotating walls. Several groups have now confirmed the basic effect [8, 9, 10, 11] but it is still unclear what physics lies behind these observations, both theoretically and experimentally [12].

First-principle calculations [13, 14] rule out the possibility of supersolidity in ideal equilibrium crystals of $^4$He. On the experimental side, no steady flow of mass through the solid phase was detected in several setups [15, 16]. It is believed that the flow detected at the melting curve in Ref. [17] was along liquid channels which form on the cell walls in contact with the grain boundaries, i.e. it was not related to the supersolid phenomenon [12].

The situation has changed radically with the recent observation of the liquid pressure equilibration by flow through a solid in the “UMass sandwich” experiment reported by Ray and Hallock [18] away from the melting curve. The dependence of the flow on the pressure difference was characteristic of critical superflow and inconsistent with the flow of a viscous liquid. In this work, we explain that the origin of superfluidity in solid $^4$He is large local strain in the vicinity of crystalline defects. Superfluidity along dislocations or grain boundaries can quantitatively account for the superflow through $^4$He crystals observed by Ray and Hallock [18].

In the past several authors have speculated about the possibility of the stress-induced supersolidity [19, 20, 21], especially under hydrostatic decompression since quantum effects and vacancy delocalization are expected to increase at lower densities. The phenomenology missed the attraction between vacancies which destabilizes a dilute homogeneous gas of vacancies. Central questions were left unanswered: what type and strength of stress is needed to close the insulating gap in $^4$He and is this stress realistic?

Our approach to this inherently strongly correlated problem is numerical. Feynman’s path-integral formulation of quantum mechanics allows an exact mapping between the $^4$He system and a system of world lines in four-dimensional space. The fourth dimension represents evolution in imaginary time and its extent is $\hbar/k_B T$ where $\hbar$ is the the reduced Planck’s constant, $k_B$ is the Boltzmann constant and $T$ is temperature. This sys-
The stability of the metastable supersolid phase depends on the sign of the effective interactions between vacancies since an attractive Bose gas is unstable: for the vacancy gas this means a collapse to the lower density liquid. To determine the sign and strength of the vacancy-vacancy interaction one has to know their mass \( m^* \) and their pair correlation function \( \nu(r) \). In the ideal gas \( \nu(r) \) is enhanced at short distances by a factor of two relative to the large distance limit. Correspondingly, for repulsive/attractive interactions \( \nu(r) \) is suppressed/enhanced relative to the ideal gas behavior. If attractive interactions are so strong that vacancies actually form a bound state, then \( \nu(r) \) is enhanced exponentially, and the decay of the correlation function with distance can be used to determine the binding energy from \( \nu(r) \propto \exp(-2m^*E_b/r) \).

In Fig. 1 we show the vacancy-vacancy correlation function, decreasing exponentially with distance. This is concrete evidence showing that interactions between vacancies are attractive and strong enough to form a bound state. From the

![Diagram](image-url)

**FIG. 1:** (Color online) Extrapolation of vacancy \((\Delta V)\) and interstitial \((\Delta I)\) gaps shows that the density corresponding to closing the gap lies in the liquid phase. The data points as a function of density for the ideal hcp solid are taken from Ref. [22]. By \( \mu\nu(\mu_I) \) we denote the threshold chemical potentials for doping the system with vacancies(interstitials).

![Diagram](image-url)

**FIG. 2:** (Color online) Vacancy dispersion relation of the lowest band along the reciprocal lattice directions \( p_x \) and \( p_z \) for a system of \( 12 \times 12 \times 12 \) particles calculated at a density \( n = 0.0292 \text{Å}^{-3} \) and temperature \( T = 0.2\text{K} \). For the hcp lattice with two atoms in the unit cell there are two hopping amplitudes, one in the basal plane \((t_\parallel)\), and one \((t_\perp)\), along the \( \Gamma A \) direction. At low temperatures the Monte Carlo method will project out the lowest branch of the dispersion relation.
exponential fit we estimate the binding energy to be $E_b = 1.4(5)\,K$. We conclude that the hcp structure at $n_c$ is kinetically unstable against collapse to the liquid state, and a supersolid in a decompressed crystals is not possible in the homogeneous setup. As a side remark we note that the equilibrium density of vacancies at finite temperature $n_V = (m^* T/2\pi)^{3/2} e^{-\Delta_V/T} \approx 0.015 \, n \, e^{-\Delta_V/T}$ involves a very small pre-exponential factor in addition to the exponential suppression, which rules out their possible role in thermodynamics at temperatures below $1K$.

**Anisotropic stress** We now turn to the study of crystals with non-zero diagonal components of the strain tensor $u_{xx}, u_{yy}$ and $u_{zz} = -u_{xx} - u_{yy}$. The phenomenology of the strain induced supersolidity in the hcp structure [20] is based on the minimal energy density allowed by symmetry: $\epsilon = (a_z - a_\perp)\,u_{zz}|\psi|^2$ for the anisotropic stress and $\epsilon = (a_z\,u_{zz} + a_\perp\,(u_{xx} + u_{yy}))|\psi|^2$ for hydrostatic stress, where $\psi$ is the superfluid order parameter. In the simulations we find (see Fig. 4) that a strain $u_{zz} = 2u_{xx} = 2u_{yy}$ of about 10-12% is necessary to close the gap for vacancy formation, and at higher strain the hcp structure collapses. Such a strain corresponds to a stress $\sigma_{zz} = C_{33} u_{zz} + C_{13} (u_{xx} + u_{yy}) = (C_{33} - C_{13}) u_{zz}$ of approximately 50 bar, hardly achievable under realistic experimental conditions. Our data shows that within error bars there is initially no dependence of the gap on anisotropic compression. Thus the linear coupling to the anisotropic strain is close to zero, $a_z \approx a_\perp$, and one has to go beyond linear theory to account for the observed effects, and the closing of the gap.

**Shear stress** By symmetry there is no linear coupling between $|\psi|^2$ and shear strain characterized by the off-diagonal components $u_{zx}, u_{yz}, u_{zy}$. The anticipated strain dependence of the gap is quadratic, $\Delta_V = \Delta_V^0 \{1 - (u_{zx}^2 + u_{zy}^2 + u_{zy}^2)/C_{44}\}$. Our results in Fig. 4 allow us to estimate the critical value of shear strain as $u_c \approx 0.15$. Using measured values of the elastic modulus $C_{44} \approx 120-130$ bar [20] the corresponding critical shear stress, $2C_{44} u_c$, for closing an insulating gap in the hcp $^4$He is about 35 bar.

**Superfluidity along crystalline defects** Even though the homogeneous strain-induced supersolid phase is unstable, it can form locally if non-uniform strain accumulating close to structural defects exceeds the critical value and destabilizes parts of the crystal. The most probable candidates for such highly strained superfluid defects are dislocations [19, 20, 21], with edge dislocations attracting most attention in the past because they produce strain coupling linearly to the superfluid order parameter. Contrary to expectations, the first evidence for superfluidity in the dislocation core was reported for screw dislocations oriented along the $\hat{z}$-direction [27]. These defects are characterized by the non-zero values of $u_{xx}$ which can be estimated by dividing the modulus of the Burgers vector $b_z = \sqrt{8/3}\,a$ by twice the circumference of the circle going through the atoms closest to the core, $4\pi a/\sqrt{3}$. The estimated strain...
The dependence on low temperature, including superfluid mass flow through the solid. The observed dependence on sample history, growth conditions, annealing and cooling procedures, indicate that crystalline defects are important for our understanding of the most quantum solid in Nature. The actual structure of defects is essentially unexplored territory, not less interesting than the solid matrix they reside in. Similar exciting phenomena occur at defects and interfaces in electronic systems [29, 30].

In this work we determined the critical values of the strain which are required to destabilize the hcp structure of $^4$He by closing its insulating gap, and find that these thresholds are small enough to be exceeded at the dislocation cores and grain boundaries. Local stresses thus hold the key to supersolidity of $^4$He.

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[1] O. Penrose, Phil. Mag. 42, 1373 (1951)